

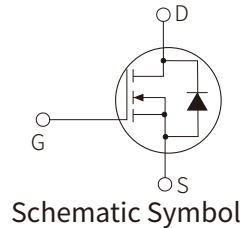
FEATURES

- | Surface-mounted package
- | Advanced trench cell design



APPLICATION

- | LCD TV appliances
- | LCDM appliances
- | High power inverter system



APPROVALS

RoHS	Compliance with 2011/65/EU
HF	Compliance with IEC61249-2-21:2003

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Drain-Source Voltage $T_c=25^\circ\text{C}$	V_{DS}	100	V
Drain Current (Pulsed) $T_c=25^\circ\text{C}$ $V_{GS}=10\text{V}$	I_{DM}^{**}	1200	A
Drain Current (DC)	I_D	$T_c=25^\circ\text{C}$ $V_{GS}=10\text{V}$	324
		$T_c=100^\circ\text{C}$ $V_{GS}=10\text{V}$	230
Gate-Source Voltage $T_c=25^\circ\text{C}$	V_{GS}	± 20	V
Drain power dissipation $T_c=25^\circ\text{C}$	P_{tot}	375	W
Junction Temperature	T_J	175	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55 to 175	$^\circ\text{C}$
Single Pulsed Avalanche Energy $V_{DD} = 50\text{V}$, $L=1.0\text{mH}$	E_{AS}	2738	mJ
Thermal Resistance – Junction to Ambient	$R_{\theta JA}^*$	45	$^\circ\text{C}/\text{W}$
Thermal Resistance- Junction to Case	$R_{\theta JC}$	0.4	$^\circ\text{C}/\text{W}$

Notes:

- * Surface Mounted on 1 in² pad area, $t \leq 10$ sec
- ** Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$
- *** Limited by bonding wire

ELECTRICAL CHARACTERISTICS (T_A=25°C)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _{DS} =250μA	100			V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _{DS} =250μA	2		4	V
Drain Leakage Current	I _{DSS}	V _{DS} =80V, V _{GS} =0V			1	μA
Gate Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V			±100	nA
On-State Resistance	R _{DS(on)} ^a	V _{GS} =10V, I _{DS} =50A		1.25	1.5	mΩ
		V _{GS} =6V, I _{DS} =30A		1.8	2.2	mΩ
Diode Characteristics						
Diode Forward Voltage	V _{SD} ^a	I _{SD} =50A, V _{GS} =0V			1.3	V
Reverse Recovery Time	t _{rr}	I _{DS} =50A, V _{GS} =0V dI _{SD} /dt=100A/μs		117		nS
Reverse Recovery Charge	Q _{rr}			273		nC
Dynamic Characteristics^b						
Input capacitance	C _{iss}	V _{GS} =0V, V _{DS} =50V, Frequency = 1 MHz		9790		pF
Output capacitance	C _{oss}			1700		pF
Reverse transfer capacitance	C _{rss}			104		pF
Turn-on Delay Time	t _{d(on)}	V _{DS} =50V, V _{GEN} =10V R _G =3.9Ω, R _L =1Ω, I _{DS} =50A		29		nS
Turn-on Rise Time	t _r			96		nS
Turn-Off Delay Time	t _{d(off)}			108		nS
Turn-Off Fall Time	t _f			96		nS
Gate Charge Characteristics^b						
Total Gate Charge	Q _g	V _{DS} =50V, V _{GS} =10V, I _{DS} =50A		173		nC
Gate-Source Charge	Q _{gs}			50		nC
Gate-Drain Charge	Q _{gd}			45		nC

Notes:

a : Pulse test ; pulse width ≤ 300us, duty cycle ≤ 2 %

b : Guaranteed by design, not subject to production testing

PARAMETER CHARACTERISTIC CURVE

Figure1: Power Capability

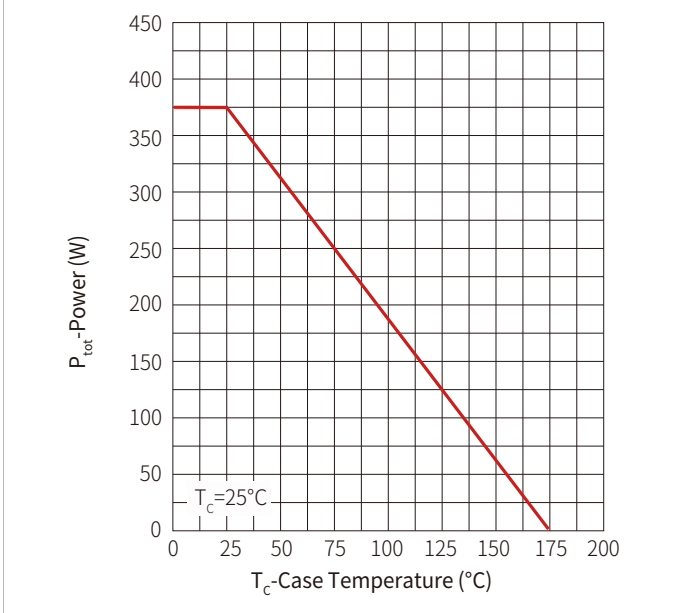


Figure2: Current Capability

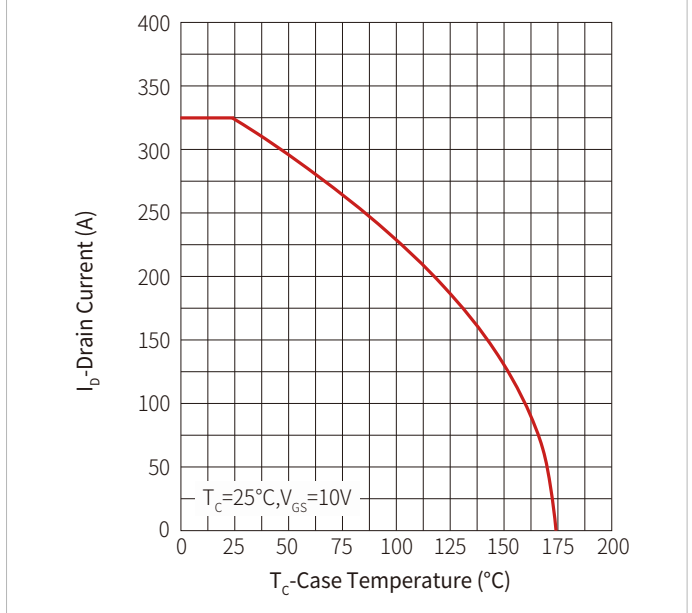


Figure3: Safe operating Area

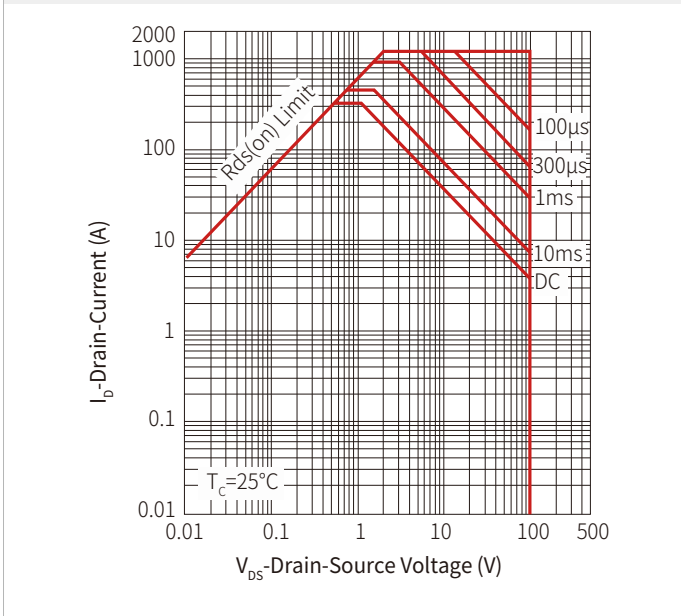


Figure 4: Transient Thermal Impedance

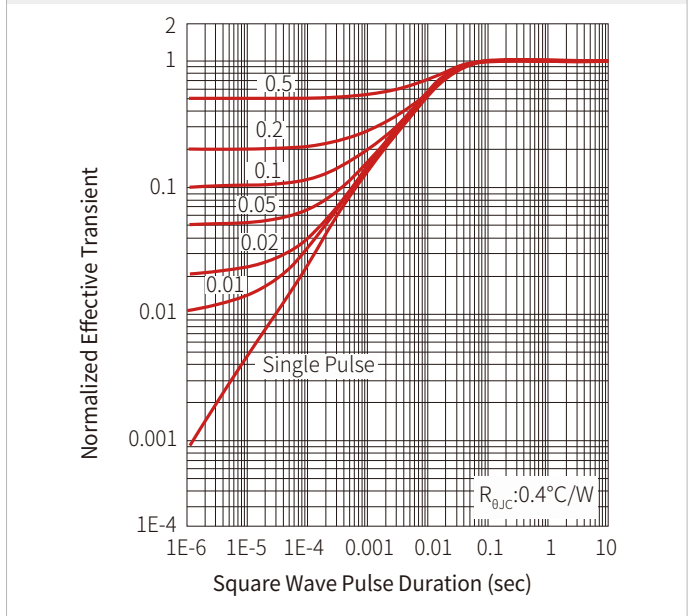


Figure 5: Output Characteristics

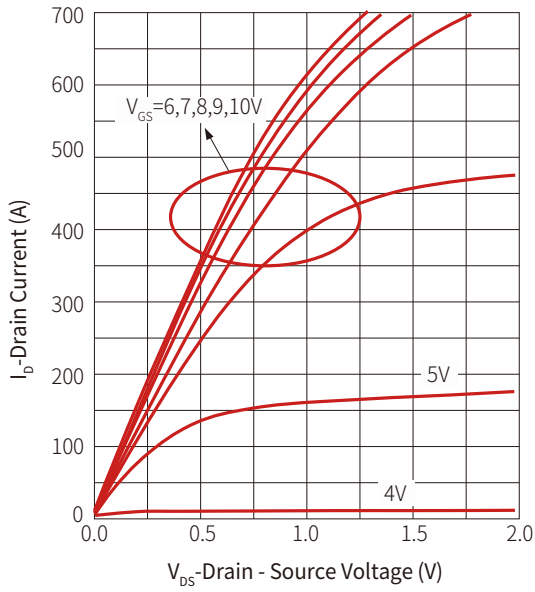


Figure 6: On Resistance

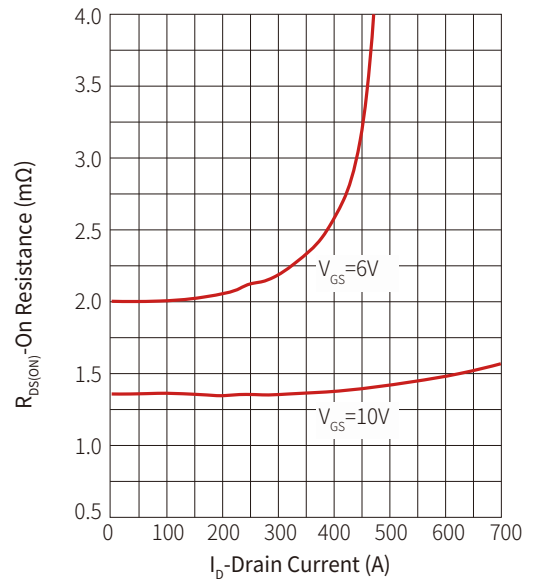


Figure 7: Transfer Characteristics

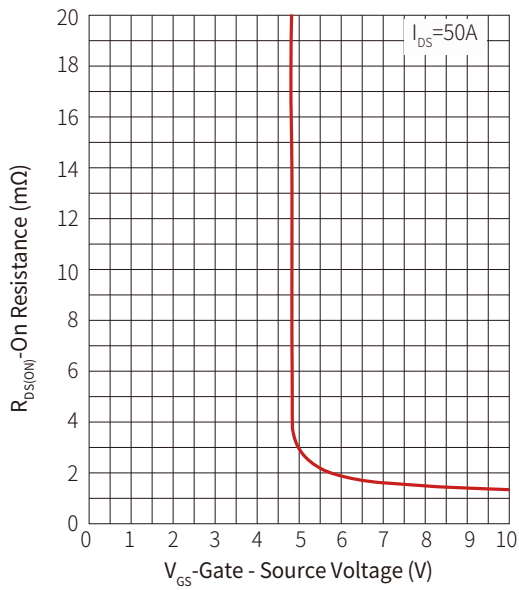


Figure 8: Normalized Threshold Voltage

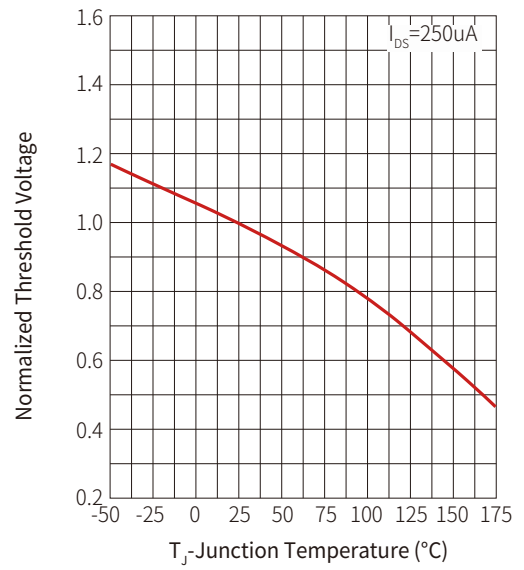


Figure 9: Normalized On Resistance

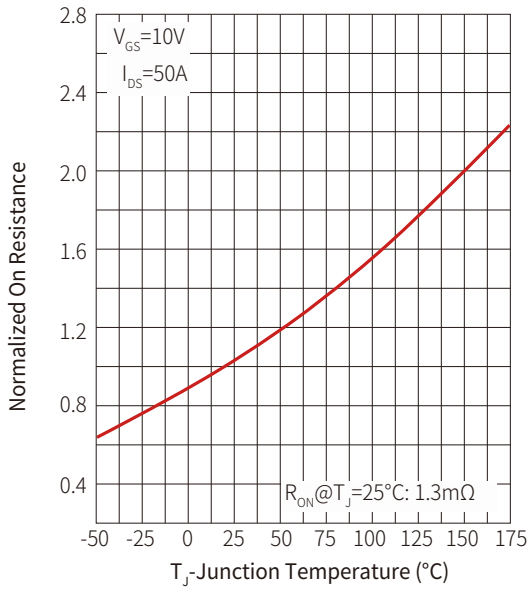


Figure 10: Diode Forward Current

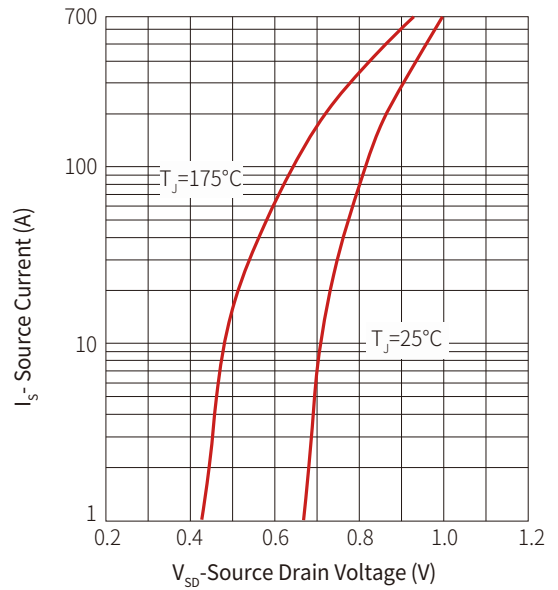


Figure 11: Capacitance

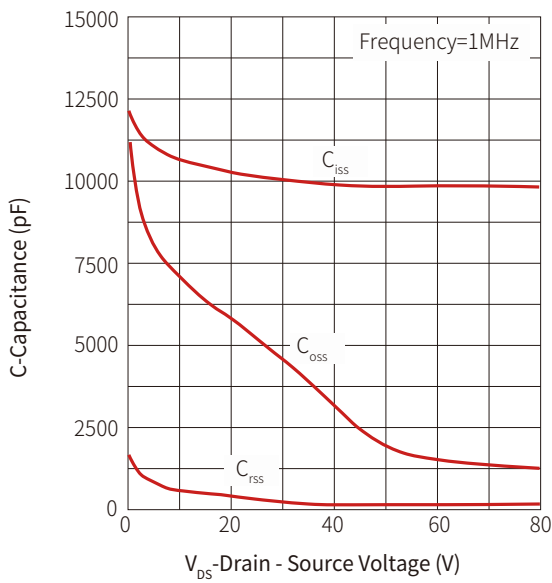
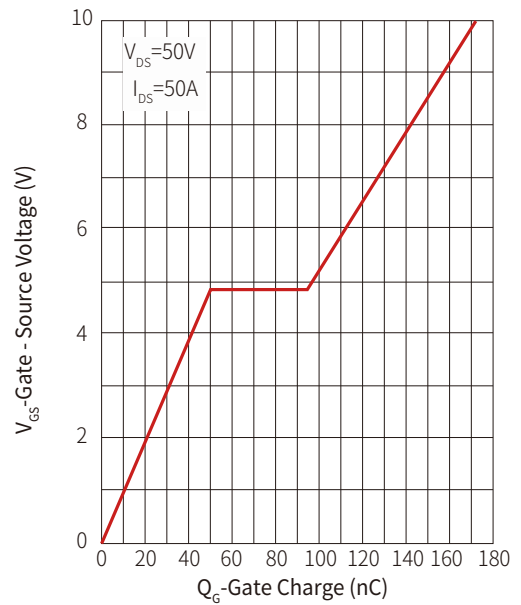
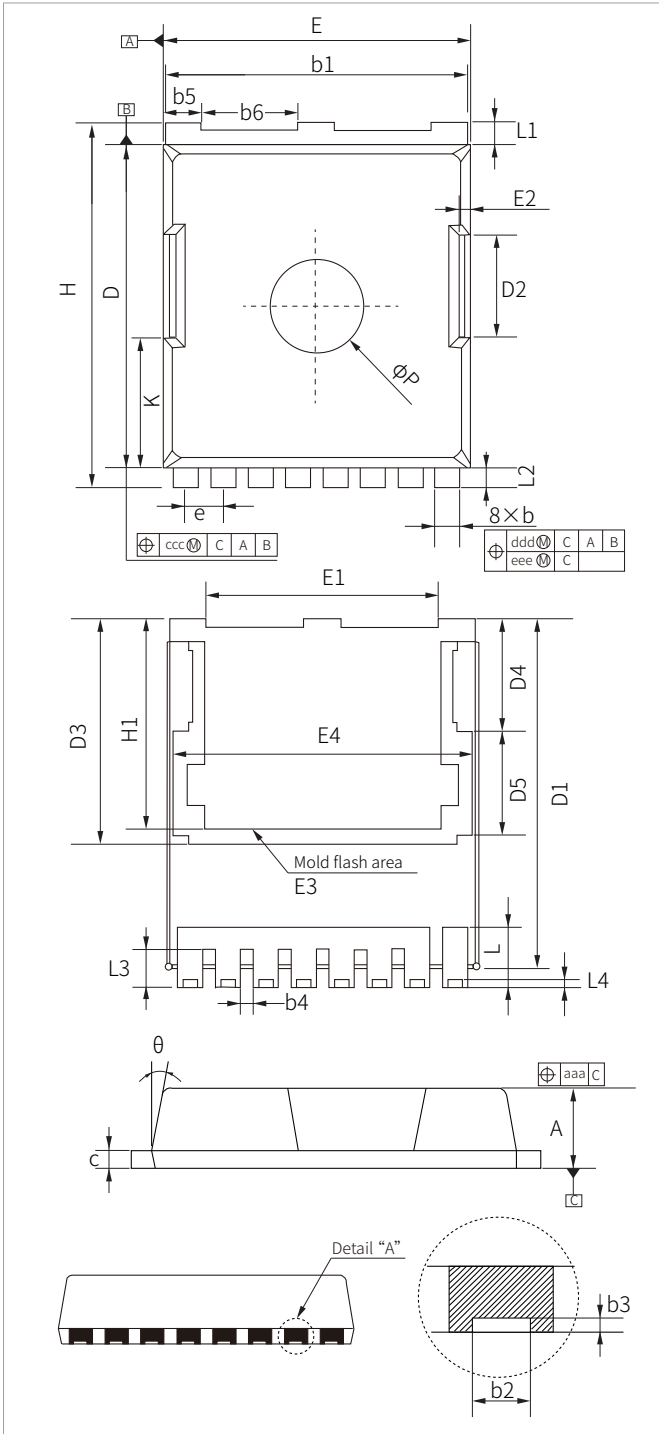


Figure 12: Gate Charge




TOLL-8L PACKAGE INFORMATION



Ref.	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	2.20	2.40	0.087	0.094
b	0.70	0.90	0.028	0.035
b1	9.70	9.90	0.382	0.390
b2	0.36	0.55	0.014	0.022
b3	0.05	-	0.002	-
b4	0.30	0.50	0.012	0.020
b5	1.10	1.30	0.043	0.051
b6	3.00	3.20	0.118	0.126
c	0.40	0.60	0.016	0.024
D	10.28	10.55	0.405	0.415
D1	10.98	11.18	0.432	0.440
D2	3.20	3.40	0.126	0.134
D3	7.15		0.281	
D4	3.59		0.141	
D5	3.26		0.128	
e	1.10	1.30	0.043	0.051
E	9.80	10.00	0.386	0.394
E1	7.40	7.60	0.291	0.299
E2	7.40	7.60	0.291	0.299
E3	8.50		0.335	
E4	9.46		0.372	
H	11.50	11.85	0.453	0.466
H1	6.55	6.75	0.258	0.266
K	4.08	4.28	0.161	0.169
L	1.60	2.10	0.063	0.083
L1	0.50	0.90	0.020	0.035
L2	0.50	0.70	0.020	0.028
L3	1.00	1.30	0.040	0.051
L4	0.13	0.33	0.005	0.013
P	2.85	3.15	0.112	0.124
theta	10°REF		0.398°REF	
aaa	0.20		0.008	
ccc	0.20		0.008	
ddd	0.25		0.010	
eee	0.20		0.008	

ORDERING INFORMATION

Part Number	Component Package	Marking	QTY/Reel	QTY/Box
SNM300N10L	TOLL-8L	 300N10 XXXX	2000PCS	14000PCS

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